



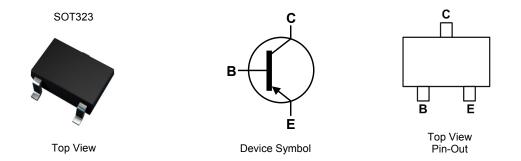
#### 20V PNP POWER SWITCHING TRANSISTOR IN SOT323

### Features

- BV<sub>CEO</sub> > -20V
- I<sub>C</sub> = -1A Continuous Collector Current
- I<sub>CM</sub> = -3A Peak Pulse Current
- Low Saturation Voltage -250mV Max @ I<sub>C</sub> = -1A.
- $R_{CE(SAT)} = 200 m\Omega$  @ 1A for a Low Equivalent On-Resistance
- 500mW Power Dissipation
- Excellent h<sub>FE</sub> Characteristics up to 3A
- Complementary NPN Type: ZUMT618
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT323
- Case Material: Molded Plastic. "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.006 grams (approximate)



#### Ordering Information (Notes 4)

Device	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per reel
ZUMT718TA	AEC-Q101	T72	7	8	3,000

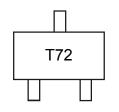
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



T72 = Product Type Marking Code



#### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-20	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-20	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Peak Pulse Current	I <sub>CM</sub>	-3	А
Continuous Collector Current	lc	-1	А
Base Current	Ι <sub>Β</sub>	-200	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	D	385	mW	
Fower Dissipation	(Note 6)	PD	500	11174	
Thermal Desistance, Junction to Ambient	(Note 5)	P	325	°C/M	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ hetaJA}$	250	°C/W	
Thermal Resistance, Junction to Leads (Note 7)		R <sub>θJL</sub>	350	°C/W	
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	٥C		

## ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with collector lead on 10mm x 8mm 1oz copper that is on a single-sided 0.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as note (5), except the collector lead is on a 25mm x 25mm 1oz copper.

Thermal resistance from junction to solder-point (at the end of the leads).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



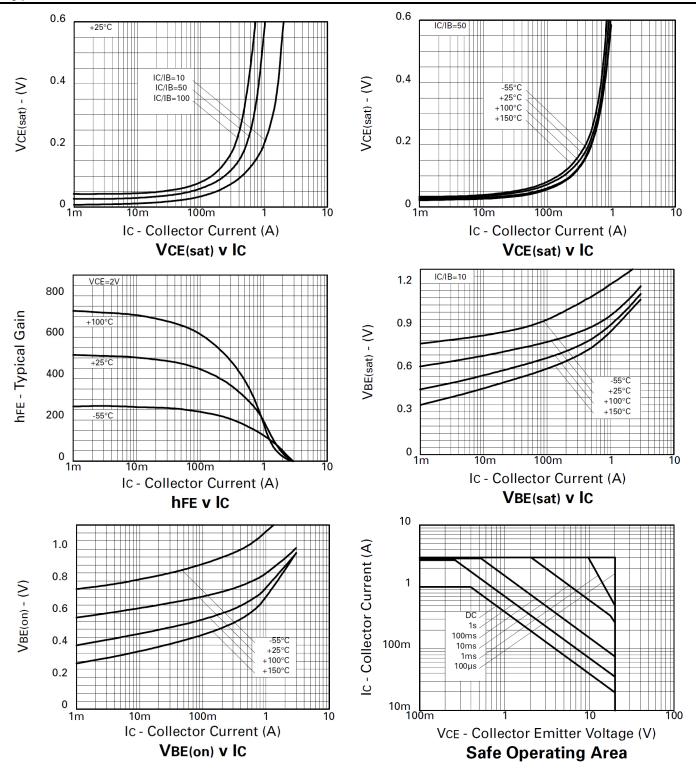
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)			•		•	•
Collector-Base Breakdown Voltage	V <sub>CBO</sub>	-20	_	_	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage	V <sub>CEO</sub>	-20	_		V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	V <sub>EBO</sub>	-7	_		V	I <sub>E</sub> = -100μA
Collector-Base Cutoff Current	I <sub>CBO</sub>	_	_	-10	nA	V <sub>CB</sub> = -15V
Emitter-Base Cutoff Current	I <sub>EBO</sub>	_	_	-10	nA	V <sub>EB</sub> = -4.0V
Collector-Emitter Cutoff Current	I <sub>CES</sub>	_	_	-10	nA	V <sub>CES</sub> = -15V
ON CHARACTERISTICS (Note 9)	· · ·					
DC Current Gain	h <sub>FE</sub>	300 300 200 100 20	490 450 315 160 75		_	$\begin{split} I_{C} &= -10 \text{mA}, \ V_{CE} &= -2.0 \text{V} \\ I_{C} &= -0.1 \text{A}, \ V_{CE} &= -2.0 \text{V} \\ I_{C} &= -0.5 \text{A}, \ V_{CE} &= -2.0 \text{V} \\ I_{C} &= -1 \text{A}, \ V_{CE} &= -2.0 \text{V} \\ I_{C} &= -1.5 \text{A}, \ V_{CE} &= -2.0 \text{V} \end{split}$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	-33.5 -80 -130 -180	-45 -110 -175 -250	mV mV mV mV	$ \begin{array}{ll} I_{C}=&-0.1A,\ I_{B}=-10mA\\ I_{C}=&-0.25A,\ I_{B}=-10mA\\ I_{C}=&-0.5A,\ I_{B}=-20mA\\ I_{C}=&-1A,\ I_{B}=-100mA \end{array} $
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	_	-970	-1100	mV	$I_{\rm C} = -1A, I_{\rm B} = 100 {\rm mA}$
Base-Emitter Turn-On Voltage	V <sub>BE(ON)</sub>	_	-850	-1100	mV	$I_{\rm C}$ = -1A, $V_{\rm CE}$ = -2.0V
SMALL SIGNAL CHARACTERISTICS						•
Output Capacitance	C <sub>obo</sub>	_	11	_	pF	V <sub>CB</sub> = -10V, f = 1MHz
Turn-On Time	t <sub>(on)</sub>	_	60		ns	V <sub>CC</sub> = -10V, I <sub>C</sub> = -1A,
Turn-Off Time	t <sub>(off)</sub>		135		ns	$I_{B1} = -I_{B2} = -100 \text{mA}$
Current Gain-Bandwidth Product	f <sub>T</sub>	_	210	_	MHz	V <sub>CE</sub> = -10V, I <sub>C</sub> = -50mA, f = 100MHz

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



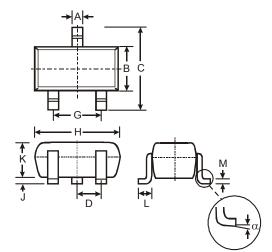
### Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)





## **Package Outline Dimensions**

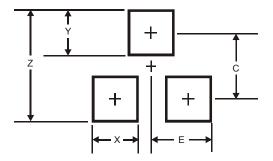
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT323						
Dim	Min	Max	Тур			
Α	0.25	0.40	0.30			
В	1.15	1.35	1.30			
С	2.00	2.20	2.10			
D	-	-	0.65			
G	1.20	1.40	1.30			
H	1.80	2.20	2.15			
J	0.0	0.10	0.05			
κ	0.90	1.00	1.00			
L 0.25 0.40 0.30						
М	0.10	0.18	0.11			
α	0°	8°	-			
All Dimensions in mm						

## Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Y	0.9
С	1.9
E	1.0



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